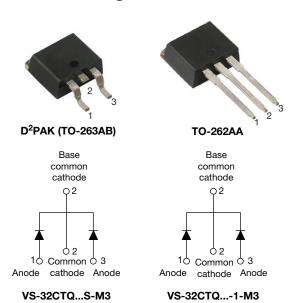
VS-32CTQ...SHM3, VS-32CTQ...-1HM3 Series

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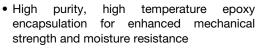
High Performance Schottky Rectifier, 2 x 15 A



PRIMARY CHARACTERISTICS						
I _{F(AV)}	2 x 15 A					
V _R	25 V, 30 V					
V _F at I _F	0.40 V					
I _{RM} typ.	97 mA at 125 °C					
T _J max.	150 °C					
E _{AS}	13 mJ					
Package	D ² PAK (TO-263AB), TO-262AA					
Circuit configuration	Common cathode					

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified meets JESD 201 class 1A whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-32CTQ... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL CHARACTERISTICS VALUES								
I _{F(AV)}	Rectangular waveform	30	А					
V _{RRM}		25, 30	V					
I _{FSM}	t _p = 5 μs sine	900	А					
V _F	15 A _{pk} , T _J = 125 °C	0.40	V					
T _J	Range	-55 to +150	°C					

VOLTAGE RATINGS							
PARAMETER SYMBOL VS-32CTQ025SHM3 VS-32CTQ030SHM3 VS-32CTQ030-1HM3 UNITS							
Maximum DC reverse voltage	V_R	25	30	V			
Maximum working peak reverse voltage	V_{RWM}	25	30	V			



VS-32CTQ...SHM3, VS-32CTQ...-1HM3 Series

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ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST COND	TEST CONDITIONS					
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 115 °C	30					
Maximum peak one cycle non-repetitive surge current	l=o	5 μs sine or 3 μs rect. pulse Following any rated load condition and with rated		900	Α			
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	250				
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1.20 A, L = 11.10 mH		13	mJ			
Repetitive avalanche current	I _{AR}	Current decaying linearly to zer Frequency limited by T_J maxim	3	Α				

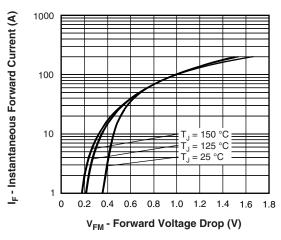
ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS				
		15 A	T _{.1} = 25 °C	0.49			
Maximum forward voltage drop	V _{FM} ⁽¹⁾	30 A	1J=25 C	0.58	V		
See fig. 1	VFM (1)	15 A	T _{.1} = 125 °C	0.40	V		
		30 A	1J = 125 C	0.53			
Maximum various laskage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V _R = rated V _R	1.75	mA		
Maximum reverse leakage current		T _J = 125 °C	VR = rated VR	145	IIIA		
Typical reverse leakage current	I _{RM} ⁽¹⁾	T _J = 125 °C	V_R = rated V_R	97	mA		
Threshold voltage	V _{F(TO)}	$T_J = T_J$ maximum		0.233	V		
Forward slope resistance	r _t	ı j = ı j maximum	9.09	mΩ			
Maximum junction capacitance per leg	C _T	V _R = 5 V _{DC} (test signal range	1300	pF			
Typical series inductance per leg	L _S	Measured lead to lead 5 m	8.0	nH			
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs		

Note

 $^{^{(1)}\,}$ Pulse width $<300~\mu s,$ duty cycle <2~%

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	YMBOL TEST CONDITIONS		UNITS		
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to +150	°C		
Maximum thermal resistance, junction to case per leg		R _{thJC}	DC operation See fig. 4	3.25	°C/W		
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50	C/VV		
Approximate weight				2	g		
Approximate weight				0.07	OZ.		
Maunting torque	minimum			6 (5)	kgf · cm		
Mounting torque	maximum			12 (10)	(lbf \cdot in)		
			Coop at the D ² DAK (TO 262AB)	32CTQ	025SH		
Marking device			Case style D ² PAK (TO-263AB)	32CTQ	030SH		
			Coop at the TO 2024 A	32CTQ	025-1H		
			Case style TO-262AA	32CTQ	32CTQ030-1H		

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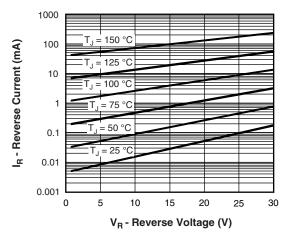


Fig. 1 - Maximum Forward Voltage Drop Characteristics

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

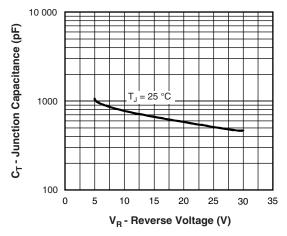


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

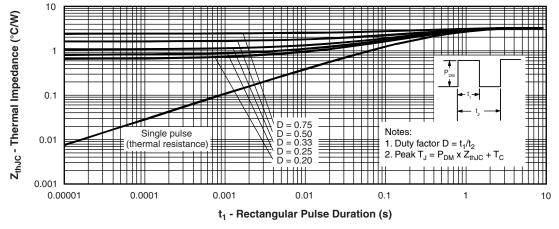


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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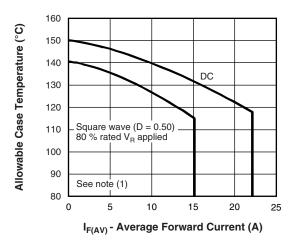


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

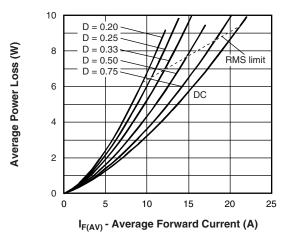


Fig. 6 - Forward Power Loss Characteristics

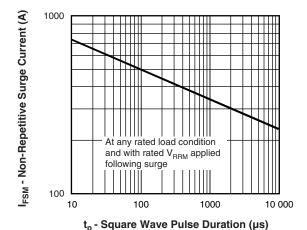


Fig. 7 - Maximum Non-Repetitive Surge Current

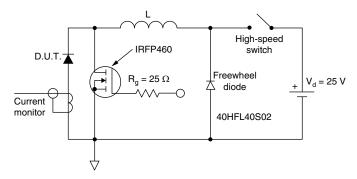


Fig. 8 - Unclamped Inductive Test Circuit

Note

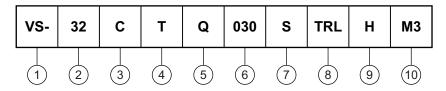
 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = 80 \text{ \% rated } V_R \\ \end{array}$

VS-32CTQ...SHM3, VS-32CTQ...-1HM3 Series

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (30 A)

3 - Circuit configuration: C = common cathode

4 - T = TO-220

5 - Schottky "Q" series

6 - Voltage ratings — 025 = 25 V 030 = 30 V

7 - • S = D²PAK

• -1 = TO-262

8 - • None = tube

• TRL = tape and reel (left oriented - for D²PAK only)

• TRR = tape and reel (right oriented - for D²PAK only)

9 - H = AEC-Q101 qualified

- M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-32CTQ025SHM3	50	1000	Antistatic plastic tubes				
VS-32CTQ025STRRHM3	800	800	13" diameter reel				
VS-32CTQ025STRLHM3	800	800	13" diameter reel				
VS-32CTQ025-1HM3	50	1000	Antistatic plastic tubes				
VS-32CTQ030SHM3	50	1000	Antistatic plastic tubes				
VS-32CTQ030STRRHM3	800	800	13" diameter reel				
VS-32CTQ030STRLHM3	800	800	13" diameter reel				
VS-32CTQ030-1HM3	50	1000	Antistatic plastic tubes				

LINKS TO RELATED DOCUMENTS						
Dimensions	D ² PAK (TO-263AB)	www.vishay.com/doc?95046				
Differsions	TO-262AA	www.vishay.com/doc?95419				
Part marking information	D ² PAK (TO-263AB)	www.vishay.com/doc?95444				
Part marking information	TO-262AA	www.vishay.com/doc?95443				
Packaging information		www.vishay.com/doc?95032				



Vishay Semiconductors

D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	OTES SYMBOL	MILLIM	ETERS	INC	HES	NOTES	
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOIES	NOTES	STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100) BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

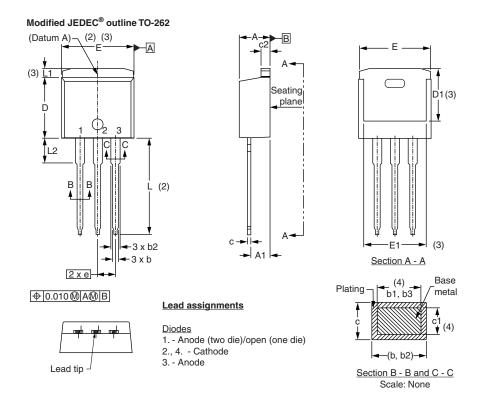
- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB



Vishay Semiconductors

TO-262

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	BSC	0.10	D BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.36	3.71	0.132	0.146	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum), D1 (minimum) and L2 where dimensions derived the actual package outline

Revision: 11-Jul-2019 1 Document Number: 95419



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